## Application Report

## TLV2314-Q1

# Functional Safety FIT Rate, FMD, and Pin FMA



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#### 1 Overview

This document contains information for TLV2314-Q1 (SOIC-8 package) to aid in a functional safety system design. Information provided are:

- Functional Safety Failure In Time (FIT) rates of the semiconductor component estimated by the application of industry reliability standards
- · Component failure modes and their distribution (FMD) based on the primary function of the device
- Pin failure mode analysis (Pin FMA)

Figure 1-1 shows the device functional block diagram for reference.

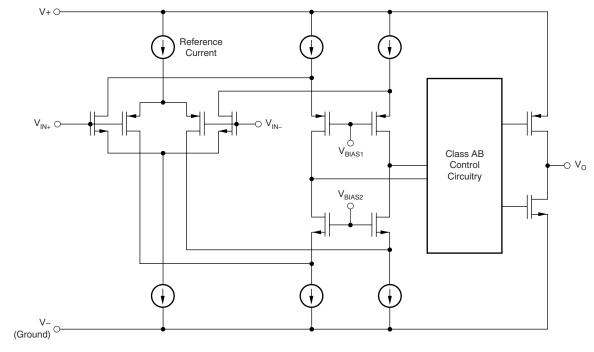


Figure 1-1. Functional Block Diagram

TLV2314-Q1 was developed using a quality-managed development process, but was not developed in accordance with the IEC 61508 or ISO 26262 standards.



## 2 Functional Safety Failure In Time (FIT) Rates

This section provides Functional Safety Failure In Time (FIT) rates for TLV2314-Q1 based on two different industry-wide used reliability standards:

- Table 2-1 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-2 provides FIT rates based on the Siemens Norm SN 29500-2

Table 2-1. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

FIT IEC TR 62380 / ISO 26262	FIT (Failures Per 10 <sup>9</sup> Hours)
Total Component FIT Rate	10
Die FIT Rate	3
Package FIT Rate	7

The failure rate and mission profile information in Table 2-1 comes from the Reliability data handbook IEC TR 62380 / ISO 26262 part 11:

Mission Profile: Motor Control from Table 11

· Power dissipation: 50 mW

Climate type: World-wide Table 8Package factor (lambda 3): Table 17b

· Substrate Material: FR4

· EOS FIT rate assumed: 0 FIT

Table 2-2. Component Failure Rates per Siemens Norm SN 29500-2

Table	Table Category		Reference Virtual T <sub>J</sub>	
4	BICMOS, Op Amps, Comparators, Voltage Monitors	8 FIT	45°C	

The Reference FIT Rate and Reference Virtual  $T_J$  (junction temperature) in Table 2-2 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



## 3 Failure Mode Distribution (FMD)

The failure mode distribution estimation for TLV2314-Q1 in Table 3-1 comes from the combination of common failure modes listed in standards such as IEC 61508 and ISO 26262, the ratio of sub-circuit function size and complexity and from best engineering judgment.

The failure modes listed in this section reflect random failure events and do not include failures due to misuse or overstress.

Table 3-1. Die Failure Modes and Distribution

Die Failure Modes	Failure Mode Distribution (%)
Out open (HIZ)	20%
Out saturate high	25%
Out saturate low	25%
Out functional not in specification or timing	30%



## 4 Pin Failure Mode Analysis (Pin FMA)

This section provides a Failure Mode Analysis (FMA) for the pins of the TLV2314-Q1. The failure modes covered in this document include the typical pin-by-pin failure scenarios:

- Pin short-circuited to Ground (see Table 4-2)
- Pin open-circuited (see Table 4-3)
- · Pin short-circuited to an adjacent pin (see Table 4-4)
- Pin short-circuited to supply (see Table 4-5)

Table 4-2 through Table 4-5 also indicate how these pin conditions can affect the device as per the failure effects classification in Table 4-1.

Table 4-1. TI	Classification	of Failure Effects
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Class	Failure Effects
А	Potential device damage that affects functionality
В	No device damage, but loss of functionality
С	No device damage, but performance degradation
D	No device damage, no impact to functionality or performance

Figure 4-1 shows the TLV2314-Q1 pin diagram. For a detailed description of the device pins please refer to the *Pin Configuration and Functions* section in the TLV2314-Q1 data sheet.

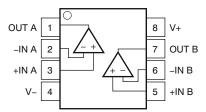


Figure 4-1. Pin Diagram

Following are the assumptions of use and the device configuration assumed for the pin FMA in this section:

Single-supply operation is used. For example, V+ = 5V and V- = 0V.

Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
OUT A	1	May cause device to overheat.	В
-IN A	2	Input at V- (GND) is valid input, however, desired application result is unlikely. Output high if +IN A is greater than zero volts.	С
+IN A	3	Input at V- (GND) is valid input, however, desired application result is unlikely. Output low if -IN A is greater than zero volts.	С
V-	4	Normal operation, unless dual supply voltage was intended.	D
+IN B	5	Input at V- (GND) is valid input, however, desired application result is unlikely. Output low if -IN B is greater than zero volts.	С
-IN B	6	Input at V- (GND) is valid input, however, desired application result is unlikely. Output high if +IN B is greater than zero volts.	С
OUT B	7	May cause device to overheat.	В



#### Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground (continued)

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
V+	8	Diodes from input to V+ may turn on due to input signal and cause electrical overstress (EOS). Main supply shorted. No power to device.	В

#### Table 4-3. Pin FMA for Device Pins Open-Circuited

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
OUT A	1	Output cannot be used by application.	С
-IN A	2	Floating input, circuit will likely not function as expected. Output may be high or low.	С
+IN A	3	Floating input, circuit will likely not function as expected. Output may be high or low.	С
V-	4	Lowest voltage pin will driv V- pin internally via internal diode.	В
+IN B	5	Floating input, circuit will likely not function as expected. Output may be high or low.	С
-IN B	6	Floating input, circuit will likely not function as expected. Output may be high or low.	С
OUT B	7	Output cannot be used by application.	С
V+	8	Highest voltage pin will drive V+ pin internally via internal diode.	В

## Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

Pin Name	Pin No.	Shorted to	Description of Potential Failure Effect(s)	Failure Effect Class
OUT A	1	-IN A	Op amp configured as unity gain buffer.	С
-IN A	2	+IN A	No damage to device. Application circuit will not work.	С
+IN A	3	V-	Input at V- (GND) is valid input, however, desired application result is unlikely. Output low if -IN A is greater than zero volts.	С
V-	4	+IN B	Input at V- (GND) is valid input, however, desired application result is unlikely. Output low if -IN B is greater than zero volts Pins are not adjacent to each other.	С
+IN B	5	-IN B	No damage to device. Application circuit will not work.	С
-IN B	6	OUT B	Op amp configured as unity gain buffer.	С
OUT B	7	V+	May cause device to overheat.	В
V+	8	OUT A	May cause device to overheat. Pins are not adjacent to each other.	В

#### Table 4-5. Pin FMA for Device Pins Short-Circuited to supply

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
OUT A	1	May cause device to overheat.	В
-IN A	2	Input at V+ is a valid input, however, desired application result is unlikely. Output goes low if +IN A is less than supply.	С
+IN A	3	Input at V+ is a valid input, however, desired application result is unlikely. Output goes high if -IN A is less than supply.	С



Table 4-5. Pin FMA for Device Pins Short-Circuited to supply (continued)

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
V-	4	Main supply shorted to V- (GND). No power to device.	В
+IN B	5	Input at V+ is a valid input, however, desired application result is unlikely. Output goes high if -IN B is less than supply.	С
-IN B	6	Input at V+ is a valid input, however, desired application result is unlikely. Output goes low if +IN B is less than supply.	С
OUT B	7	May cause device to overheat.	В
V+	8	Normal operation.	D

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